

P/N: DI-5YWB

YELLOW

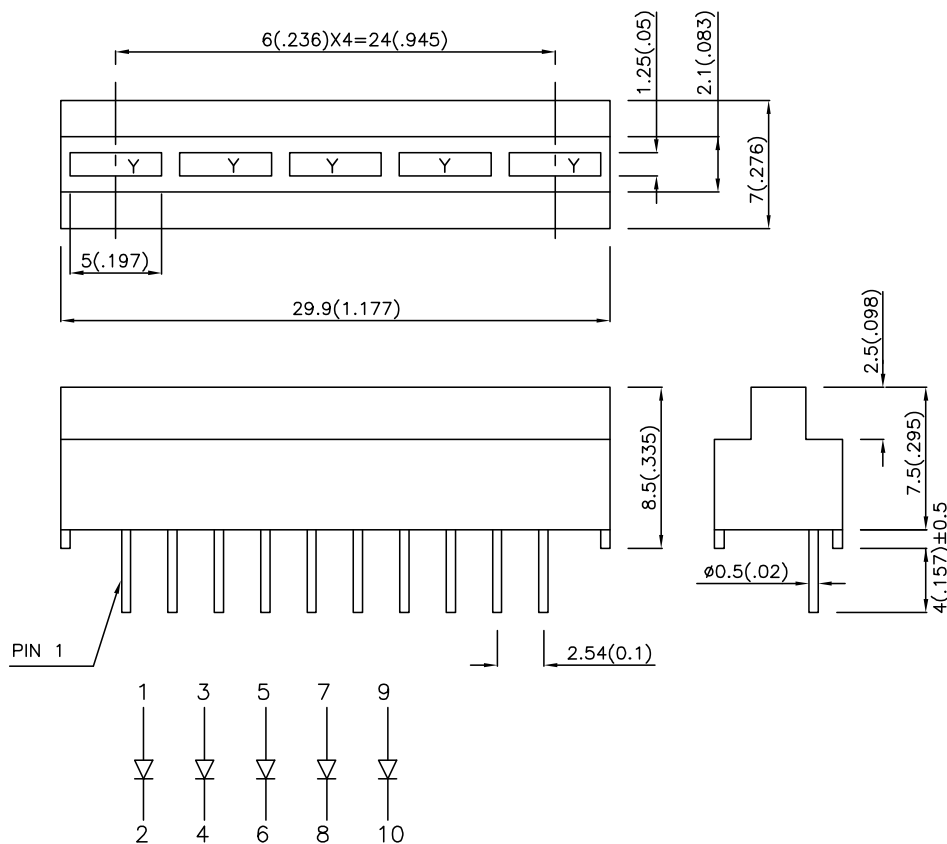
Features

- SUITABLE FOR LEVEL INDICATORS.
- LOW CURRENT OPERATION.
- EXCELLENT ON/OFF CONTRAST.
- MECHANICALLY RUGGED.
- DIFFERENT COLORS IN ONE UNIT AVAILABLE.
- STANDARD :BLACK FACE, WHITE SEGMENT.
- RoHS COMPLIANT.

Description

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
DI-5YWB	YELLOW (GaAsP/GaP)	WHITE DIFFUSED	800	2200	5 Segments Bargraph-Display

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Yellow	590		nm	IF=20mA
λ_D [1]	Dominant Wavelength	Yellow	588		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Yellow	35		nm	IF=20mA
C	Capacitance	Yellow	20		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Yellow	2.1	2.5	V	IF=20mA
IR	Reverse Current	Yellow		10	uA	VR = 5V

Notes:

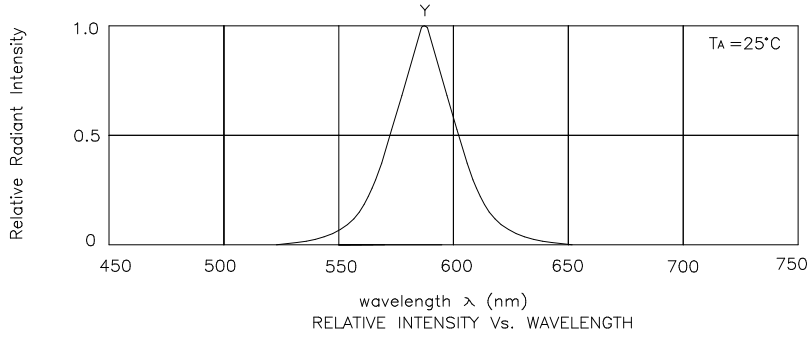
- 1.Wavelength: +/-1nm.
2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

Parameter	Yellow	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	140	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



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